Form PTO-1449 (modified)

Atty. Docket No. 2000.071100/SFD

Serial No. 09/897,576

List of Patents and Publications for A

INFORMATION DISCLOSURE STATEMENT

Richard J. Markle, et al.

Filing Date: July 2, 2001

Applicants

Group: 2877

(Use several sheets if necessary) **U.S. Patent Documents**

Foreign Patent Documents See Page 1

Other Art See Page 1-2

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Exam. Init.	Ref. Des.	Citation
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	C3	(C) 7
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Atty. Docket No. 2000.071100/SFD

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List of Patents and Publications for Applicant's

Applicants

Richard J. Markle, et al.

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•		Richard J. Markle, et	al.
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